NSN 5961-01-545-6864

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-545-6864 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Overall Height:** Between 0.091 inches and 0.103 inches Overall Width: Between 0.091 inches and 0.103 inches **End Application:** Processor, cca; mcm 9-14 aft deck equipment **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 regulator voltage and 12.0 reverse voltage, peak and 15.75 regulator voltage, dc at rated current **Current Rating Per Characteristic:** 95.00 amperes all primaries preset **Product Name:** Inavy: semiconductor dev **Special Features:** Surface mount; square end cap **Test Data Document:** 81349-mil-s-19500/406c specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**